

### **MMBT3906M PNP General Purpose Transistor**

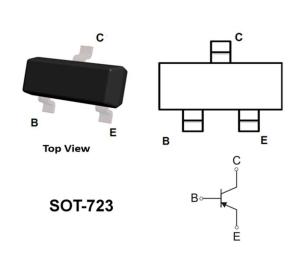
### **General description**

• PNP General Purpose Transistor

#### **FEATURES**

- SOT-723 General Purpose Transistors.
- VCEO -40V
- -200mA Ic
- PC 100mW
- Complementary to MMBT3904MSmall Outline Surface Mount Package.
- RoHS Compliant / Green EMC.

Туре	MMBT3904M
Marking	3N



### Absolute Maximum Ratings(Ta=25°C)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	Vсво	-40	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-40	V
Emitter-Base Voltage	VEBO	5	V
Collector Current -Continuous	Ic	-0.2	А
Power Dissipation	Pc	0.1	W
Thermal Resistance from Junction to Ambient	R <sub>θ</sub> JA	1250	°C/W
Junction Temperature	TJ	150	$^{\circ}$
Storage Temperature	Тѕтс	-55∼+150	°C



## ELECTRICAL CHARACTERISTICS @ 25°C Unless Otherwise Specified

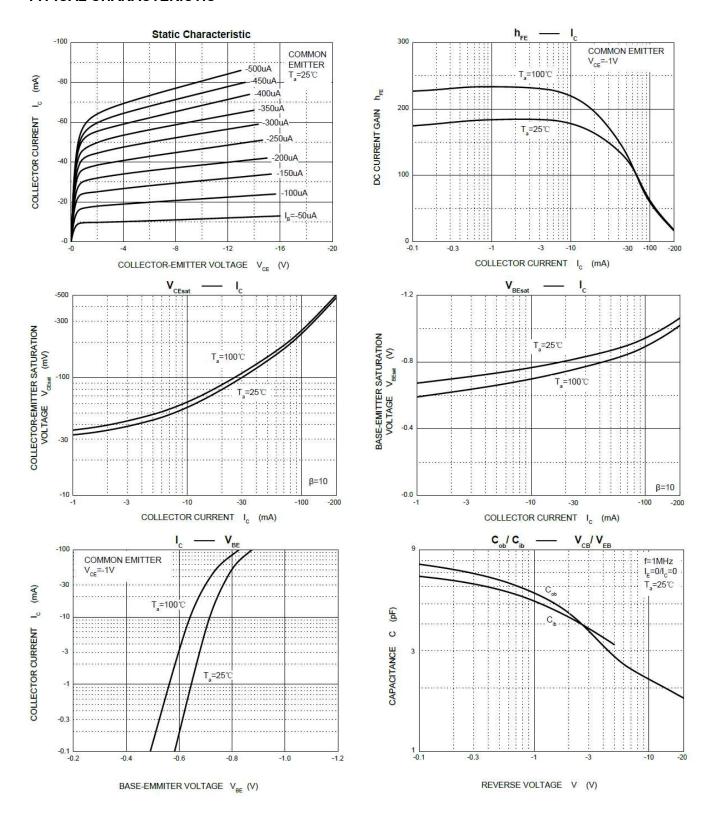
Parameter	Symbol	Conditions	Min	Тур	Max	Units
Collector-base breakdown voltage	V(BR)CBO	Ic=10μA,Iε=0	-40			V
Collector-emitter breakdown voltage	V(BR)CEO	Ic=1mA,I <sub>B</sub> =0	-40			٧
Emitter-base breakdown voltage	V(BR)EBO	Iε=10μA,Ic=0	-5			٧
Collector cut-off current	ICEX	VCE=-30V,VEB(off)=-3V			-50	nA
Emitter cut-off current	ІЕВО	V <sub>EB</sub> =-5V,I <sub>C</sub> =0			-100	nA
DC current gain	hfe	VcE=-1V,Ic=-0.1mA	40			
		Vc=-1V,Ic=-1mA	70			
		Vce=-1V,Ic=-10mA	100		300	
		Vc=-1V,Ic=-50mA	60			
		Ic=-10mA,I <sub>B</sub> =-1mA			-0.2	V
Collector-emitter saturation voltage	VCE(sat)	Ic=-50mA,I <sub>B</sub> =-5mA			-0.3	V
Base-emitter saturation voltage	V <sub>BE</sub> (sat)	Ic=-10mA,Iв=-1mA	-0.65		-0.85	V
		Ic=-50mA,Iв=-5mA			-0.95	V
Transition frequency	fτ	V <sub>CE</sub> =-20V,I <sub>C</sub> =-10mA,f=100MHz	300			MHz
Output capacitance	Сор	VcB=-5V,IE=0,f=1MHz			4	pF
Input capacitance	Cib	VEC =-0.5V,Ic=0,f=1MHz			8	pF
Noise figure	NF	$V_{CE}$ =-5 $V$ , $I_{C}$ =- 0.1 $m$ A, $f$ =1 $M$ Hz, $R_{S}$ =1 $k$ Ω			5	dB



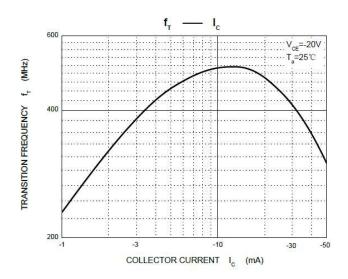
Parameter	Symbol	Conditions	Min	Тур	Max	Units
Delay time	<b>t</b> d				35	ns
Rise time	t <sub>r</sub>	Vcc=-3V,V <sub>BE(off)</sub> =-0.5V, Ic=- 10mA,I <sub>B1</sub> =-1mA			25	ns
Storage time	ts	Vcc=-3V,lc=-10mA l <sub>B1</sub> =l <sub>B2</sub> =-			225	ns
Fall time	t <sub>f</sub>	1mA			75	ns

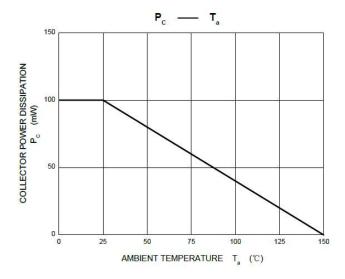


### TYPICAL CHARACTERICTIC

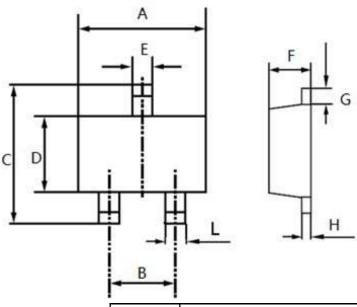








#### **PACKAGE DIMENSIONS**



Symbol	Dimensions In Millimeters			
Symbol	Min	Max		
Α	1.100	1.300		
В	0.8typ			
С	1.100	1.300		
D	0.700	0.900		
E	0.200	0.300		
F	0.400	0.500		
G	0.150	0.250		
Н	0.060	0.160		
L	0.150	0.250		



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